

- Ideal for 307.3 MHz Transmitters
- Very Low Series Resistance
- Quartz Stability
- Surface-mount Ceramic Case
- Complies with Directive 2002/95/EC (RoHS)



The RO3123A is a true one-port, surface-acoustic-wave (SAW) resonator in a surface-mount, ceramic case. It provides reliable, fundamental-mode, quartz frequency stabilization of fixed-frequency transmitters operating at 307.3 MHz.

Absolute Maximum Ratings

Rating	Value	Units
CW RF Power Dissipation (See: Typical Test Circuit)	+0	dBm
DC Voltage Between Terminals (Observe ESD Precautions)	±30	VDC
Case Temperature	-40 to +85	°C
Soldering Temperature (10 seconds / 5 cycles maximum)	260	°C

SAW Resonator



Electrical Characteristics

Characteristic		Sym	Notes	Minimum	Typical	Maximum	Units
Center Frequency, +25 °C	Absolute Frequency	f _C	0045	307.200		307.400	MHz
	Tolerance from 307.3 MHz	Δf_{C}	2,3,4,5			±100	kHz
Insertion Loss		IL	2,5,6		0.9	1.5	dB
Quality Factor	Unloaded Q	Q _U	5,6,7		16400		
	50 Ω Loaded Q	QL			1400		
Temperature Stability	Turnover Temperature	Т _О	6,7,8	10	25	40	°C
	Turnover Frequency	f _O			f _C		
	Frequency Temperature Coefficient	FTC			0.032		ppm/°C ²
Frequency Aging	Absolute Value during the First Year	f _A	1		≤10		ppm/yr
DC Insulation Resistance between Any Two Terminals			5	1.0			MΩ
RF Equivalent RLC Model	Motional Resistance	R _M			9.8		Ω
	Motional Inductance	L _M	5, 7, 9		83		μH
	Motional Capacitance	C _M			3.2		fF
	Shunt Static Capacitance	CO	5, 6, 9		3.0		pF
Test Fixture Shunt Inductance		L _{TEST}	2, 7		89		nH
Lid Symbolization (in addition to Lot and/or Date Codes)			•	831	// YWWS	•	•

8.

CAUTION: Electrostatic Sensitive Device. Observe precautions for handling. Notes:

Frequency aging is the change in f_{C} with time and is specified at +65 $^{\circ}\text{C}$ or 1.

- less. Aging may exceed the specification for prolonged temperatures above +65 °C. Typically, aging is greatest the first year after manufacture, decreasing in subsequent years. The center frequency, f_C, is measured at the minimum insertion loss point, IL_{MIN}, with the resonator in the 50 Ω test system (VSWR \leq 1.2:1). The 2 shunt inductance, L_{TEST} , is tuned for parallel resonance with C_O at f_C . Typically, f_{OSCILLATOR} or f_{TRANSMITTER} is approximately equal to the resonator f_C.
- One or more of the following United States patents apply: 4,454,488 and 3. 4.616.197.
- 4 Typically, equipment utilizing this device requires emissions testing and government approval, which is the responsibility of the equipment manufacturer.
- 5 Unless noted otherwise, case temperature $T_C = +25 \pm 2$ °C.
- The design, manufacturing process, and specifications of this device are 6. Subject to change without notice. Derived mathematically from one or more of the following directly
- 7.

measured parameters: f_C , IL, 3 dB bandwidth, f_C versus T_C , and C_O . Turnover temperature, T_O, is the temperature of maximum (or turnover) frequency, f_O. The nominal frequency at any case temperature, T_C, may be calculated from: $f = f_0 [1 - FTC (T_0 - T_C)^2]$. Typically oscillator T_0 is approximately equal to the specified resonator T_0 .

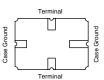
- 9 This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance Co is the static (nonmotional) capacitance between the two terminals measured at low frequency (10 MHz) with a capacitance meter. The measurement includes parasitic capacitance with "NC" pads unconnected. Case parasitic capacitance is approximately 0.05 pF. Transducer parallel capacitance can by calculated as: $C_P \approx C_0 \cdot 0.05$ pF.
- 10. Tape and Reel standard per ANSI / EIA 481.

RO3123A

307.3 MHz

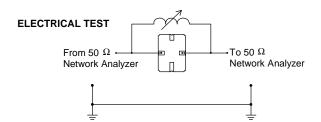
Electrical Connections

The SAW resonator is bidirectional and may be installed with either orientation. The two terminals are interchangeable and unnumbered. The callout NC indicates no internal connection. The NC pads assist with mechanical positioning and stability. External grounding of the NC pads is recommended to help reduce parasitic capacitance in the circuit.

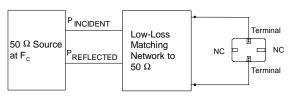


Typical Test Circuit

The test circuit inductor, L_{TEST}, is tuned to resonate with the static capacitance, C_O, at F_C.



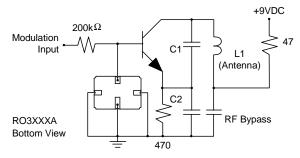
POWER TEST



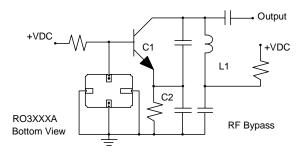
PINCIDENT - P REFLECTED CW RF Power Dissipation =

Typical Application Circuits

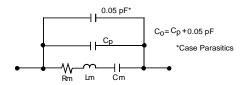
Typical Low-Power Transmitter Application



Typical Local Oscillator Applications



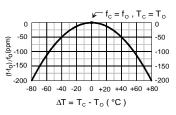
Equivalent Model



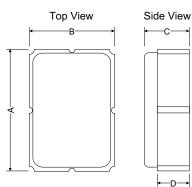
-C

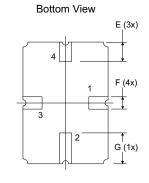
Temperature Characteristics

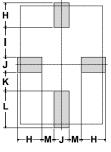
The curve shown on the right accounts for resonator contribution only and does not include LC component temperature contributions.



Case







-D-

PCB Land Pattern Top View

Dimensions	N	lillimeter	s	Inches			
Dimensions	Min	Nom	Max	Min	Nom	Max	
А	4.87	5.00	5.13	0.191	0.196	0.201	
В	3.37	3.50	3.63	0.132	0.137	0.142	
С	1.45	1.53	1.60	0.057	0.060	0.062	
D	1.35	1.43	1.50	0.040	0.057	0.059	
E	0.67	0.80	0.93	0.026	0.031	0.036	
F	0.37	0.50	0.63	0.014	0.019	0.024	
G	1.07	1.20	1.33	0.042	0.047	0.052	
Н	-	1.04	-	-	0.041	-	
I	-	1.46	-	-	0.058	-	
J	-	0.50	-	-	0.019	-	
K	-	1.05	-	-	0.041	-	
L	-	1.44	-	-	0.057	-	
М	-	0.71	-	-	0.028	-	

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for murata manufacturer:

Other Similar products are found below :

 786028C
 MGJ1D121905MPC-R7
 MGJ2D051515SC
 82103C
 82224C
 82473C
 GCM32EC71H106MA03L
 GRM2165C1H101FA01D

 PTGL09AS2R2K3B51B0
 11R683C
 DD1274AS-H-220M=P3
 DFE252012P-1R0M=P2
 BPM15-120-Q12P-C
 NMK1212SC
 NMV1212DAC

 LQH43MN330J03L
 GRM1885C1H150FA01J
 GRM21BR71C475KE51L
 GRM3195C2A471JD01D
 GRM31CR61A475KA01L
 RF1211C

 MGJ2D121509SC
 MGJ6D122005LMC-R7
 #B953AS-330M=P3
 BLM18AG601SN1J
 HN-214X
 TZ03P450
 UEE-12/12.5-D48NB-C

 LBWB1ZZYDZ-DTEMP-SNIC-UART-A
 LLM315R70J225MA11L
 46334C
 DR4103
 SCA830-D07-PCB
 NKE1212DC
 NMA1215SC

 UVQ-48/2.5-D24PB-C
 RDE5C1H472J1M1H03A
 IML-0642
 HPR105C
 HPQ-12/25-D48PB-C
 UWS-5/10-Q48N-C
 UWR-5/2000-D24E-C

 19R683C
 UHE-152000-D24-C
 782485/35C
 UEI-3.3/15-Q12PR-C
 MGJ2D122005SC
 MEW1S0505SC
 MEMS-EVAL-BOARD